## NSN 5961-01-072-9781

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-072-9781 **Inclosure Material:** Plastic **Overall Length:** Between 0.185 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.100 inches and 0.107 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 working peak reverse voltage and 200.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited and 20.0 reverse voltage, total rms **Current Rating Per Characteristic:** 1.00 amperes average forward current averaged over a full 60-hz cycle and 20.00 amperes peak forward surge current **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: